

14701 Firestone Blvd * La Mirada, Ca 90638 Phone: (562) 404-4474 * Fax: (562) 404-1773 ssdi@ssdi-power.com * www.ssdi-power.com

Designer's Data Sheet Part Number/Ordering Information ^{1/} SDR95 [⊥] Screening ^{⊉/} = Not Screened TX = TX Level TXV = TXV Level S = S Level Lead Bend Option (See Figure 1) = Straight Leads UB = Up Bend DB = Down Bend **Package** M = TO-254. Z = TO-254Z Voltage 3 = 300V 4 = 400V5 = 500V 6 = 600V

SDR953M & Z Thru **SDR956M & Z**

50 Amp Hyper Fast Rectifier 300 - 600 Volts, 35 nsec

Features:

- Hyper Fast Recovery: 35 nsec Maximum ^{3/} •
- High Surge Rating
- Low Reverse Leakage Current •
- Low Junction Capacitance
- Hermetically Sealed Low Profile Package
- Gold Eutectic Die Attach Available
- Ultrasonic Aluminum Wire Bonds
- Higher Voltages and Faster Recovery Times Available, Contact Factory
- Ceramic Seal for Improved Hermeticity Available
 - TX, TXV, and S-Level Screening Available^{2/}

Maximum Ratings		Symbol	Value	Units
Peak Repetitive Reverse Voltage And DC Blocking Voltage	SDR953M & Z SDR954M & Z SDR955M & Z SDR956M & Z	V _{RRM} V _{RWM} V _R	300 400 500 600	V
Average Rectified Forward Current (Resistive Load, 60 Hz Sine Wave, $T_A = 25^{\circ}C$)		lo	50	Α
Peak Surge Current ^{_5/} (8.3 ms Pulse, Half Sine Wave, or equivalent DC) ^{4/}		I _{FSM}	450	Α
Operating & Storage Temperature		T _{OP} & T _{STG}	-65 to +200	Ĵ
Maximum Total Thermal Resistance Junction to Case		R _{θJC}	1.2	°C/W

Notes:

1/ For ordering information, price, operating curves, and availability- contact factory.

2/ Screening based on MIL-PRF-19500. Screening flows available on request.

3/ Recovery conditions: $I_F = .5$ Amp, $I_R = 1A$, $I_{RR} = .25A$.

4/ Pins 2 and 3 tied together.

5/ Available with higher surge ratings.



TO-254 (M)

TO-254Z (Z)





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Electrical Characteristics			Мах	Units
Instantaneous Forward Voltage Drop $(I_F = 25 \text{ A}, \text{Pulse})$ $(I_F = 50 \text{ A}, \text{Pulse})$	$T_{A} = 25^{\circ}C$ $T_{A} = 25^{\circ}C$	V _{F1} V _{F2}	1.30 1.65	V _{DC}
Instantaneous Forward Voltage Drop (I _F = 25 Adc, Pulse)	$T_A = -55^{\circ}C$ $T_A = 100^{\circ}C$	V _{F3} V _{F4}	1.4 1.2	V _{DC}
Reverse Leakage Current	T_A = 25°C, Rated V _R , Pulse T_A = 100°C, 80% Rated V _R Pulse	I _{R1} I _{R2}	200 10	μA mA
Reverse Recovery Time $(I_F = .5 A, I_R = 1 A, I_{RR} = .25 A)$	T _A = 25°C	t _{RR}	35	nsec
Junction Capacitance (V_R = 10 V_{DC} , T_A = 25°C, f = 1 MHz)		CJ	250	pF





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PIN ASSIGNMENT (TO-254 and TO-254Z)							
Code	FUNCTION	Pin 1	Pin 2	Pin 3			
		Cathode	Anode	Anode			

